

Engineering/Process Change Notice

ECN/PCN No.: 4160

For Manufacturer					
Product Description: PLASTIC SMD MEMS OSCILLATOR	Abracon Part Number / Part Series: EMS43	☐ Documentation only☐ ECN☐ EOL	⊠ Series □ Part Number		
Affected Revision:	New Revision:	Application:	☐ Safety		
E	EOL		Non-Safety		
Prior to Change:					
Active					
After Change:					
EOL					
Cause/Reason for Change:					
Discontinuation of manufacturing capabilit	ty.				
	Change Plan				
Effective Date:	Additional Remarks:				
2/7/2022	N/A				
Change Declaration: N/A					
Issued Date: 2/7/2022	Issued By:	Issued Department:			
Approval:	Approval:	Approval:			
	For Abracon EOL only				
Last Time Buy (if applicable):	Alternate Part Num	her / Part Series			
5/7/2022	Alternate Fare Nam	none			
Additional Approval:	Additional Approval:	Additional Approval:			
Additional Approval.	Additional Approval.	Additional Approval.			
	Customer Approval (If Applicable)				
Qualification Status:	Customer ripprotein (it rippinounts)				
Qualification Status: Approved Not accepted					
Note: It is considered approved if there is no feedback from the customer 1 month after ECN/PCN is released.					
Customer Part Number:	Customer Project:				
Company Name:	Company Representative:	Representative Signature	:		
Customer Remarks:					

Form #7020 | Rev. G | Effective: 02/22/2021 |













EMS43 Series



REGULATORY COMPLIANCE











ITEM DESCRIPTION

Spread Spectrum MEMS Clock Oscillators LVCMOS (CMOS) 3.3Vdc 4 Pad 2.0mm x 2.5mm Plastic Surface Mount (SMD)

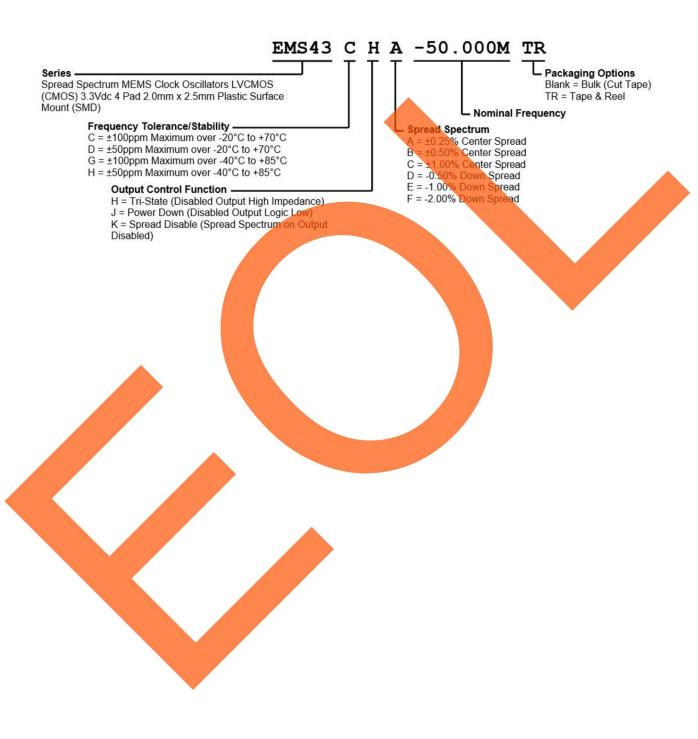
ELECTRICAL SPECIFICAT	TIONS	
Nominal Frequency	1MHz to 175MHz	
Frequency Tolerance/Stability	Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration ±100ppm Maximum over -20°C to +70°C ±50ppm Maximum over -20°C to +70°C ±100ppm Maximum over -40°C to +85°C ±50ppm Maximum over -40°C to +85°C	
Aging at 25°C	±1ppm Maximum First Year	
Supply Voltage	3.3Vdc ±10%	
Maximum Supply Voltage	-0.5Vdc to +3.65Vdc	
Input Current	Unloaded; Nominal Vdd 30mA Maximum over Nominal Frequency of 1MHz to 25MHz 40mA Maximu <mark>m over</mark> Nominal Frequency of 25.000001MHz to 175MHz	
Output Voltage Logic High (V _{он})	IOH=-8mA 90% of Vdd Minimum	
Output Voltage Logic Low (V _{OL})	IOL=+8mA 10% of Vdd M <mark>aximum</mark>	
Rise/Fall Time	Measured from 20% to 80% of waveform 2nSec Maximum	
Duty Cycle	Measured at 50% of waveform 50 ±5(%) over Nominal Frequency of 1MHz to 75MHz 50 ±10(%) over Nominal Frequency of 75.000001MHz to 175MHz	
Load Drive Capability	15pF Maximum	
Output Logic Type	CMOS	
Output Control Function	Tri-State (Disabled Output High Impedance) Power Down (Disabled Output Logic Low) Spread Disable (Spread Spectrum On Output Disabled)	
Power Down Input Voltage	70% of Vdd Minimum or No Connection to Enable Output,	
(Vih and Vil) Tri-State Input Voltage	30% of Vdd Maximum to Disable Output (Disabled Output Logic Low) 70% of Vdd Minimum or No Connection to Enable Output,	
(Vih and Vil)	30% of Vdd Maximum to Disable Output (Disabled Output High Impedance)	
Disable Current	Pad 1=Ground 20mA Maximum (Disabled Output: High Impedance)	
Standby Current	Pad 1=Ground 50µA Maximum (Disabled Output: Logic Low)	
Spread Spectrum Input Voltage	70% of Vdd Minimum or No Connection to Enable Spread Spectrum-On Output,	
(Vih and Vil)	30% of Vdd Maximum to Disable Spread Spectrum-On Output (Spread Spectrum On Output Disabled)	
Spread Spectrum	 ±0.25% Center Spread (Not available with Output Control Function of Spread Disable) ±0.50% Center Spread (Not available with Output Control Function of Spread Disable) ±1.00% Center Spread (Not available with Output Control Function of Spread Disable) -0.50% Down Spread -1.00% Down Spread -2.00% Down Spread -2.00% Down Spread 	
Modulation Frequency	30kHz Minimum, 32kHz Typical, 35kHz Maximum	
Period Jitter	Cycle to Cycle; Spread Spectrum-On; Fo=133.333M, Vdd=3.3Vdc 30pSec Maximum	
Start Up Time	10mSec Maximum	



Storage Temperature Range

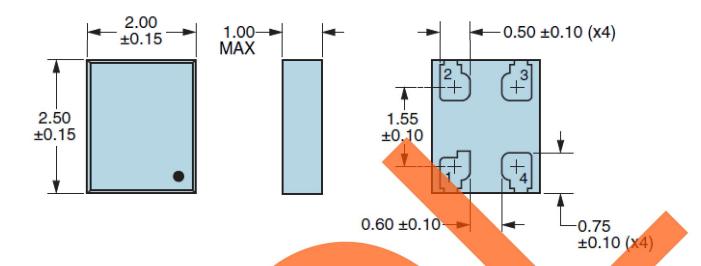
-55°C to +125°C

PART NUMBERING GUIDE

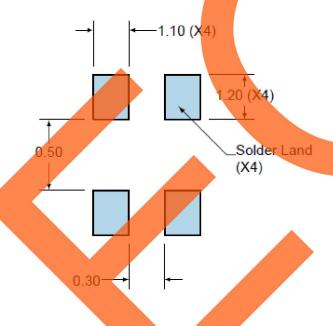




MECHANICAL DIMENSIONS



SUGGESTED SOLDER PAD LAYOUT



PIN	CONNECTION
1	Power Down Or Spread Disable Or Tri-State
2	Ground
3	Output
4	Supply Voltage

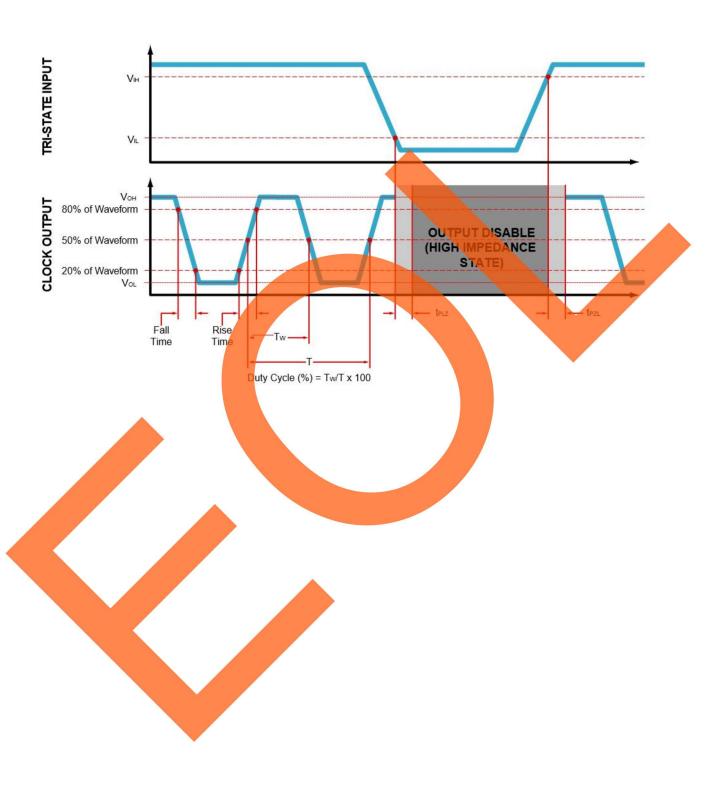
All Tolerances are ±0.1

All Dimensions in Millimeters

EMS43 Series

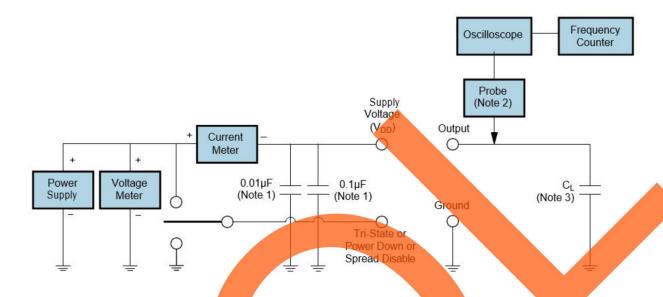


OUTPUT WAVEFORM & TIMING DIAGRAM





TEST CIRCUIT FOR CMOS OUTPUT



Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less Than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low capacitance (<12pF), 10X Attenuation Factor, High Impedance (>10Mohms), and High bandwidth (>300MHz) Passive probe is recommended.

Note 3: Capacitance value CL includes sum of all probe and fixture capacitance

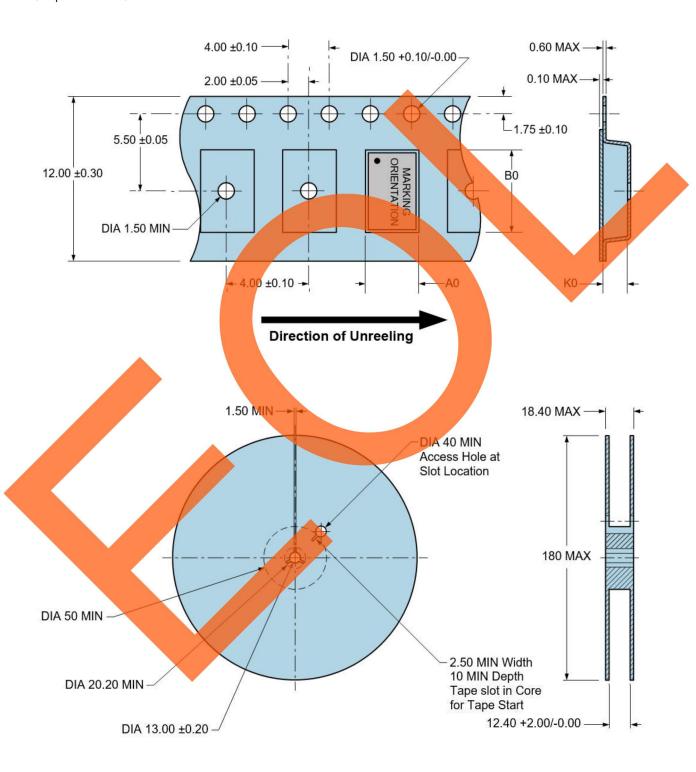
EMS43 Series



TAPE & REEL DIMENSIONS

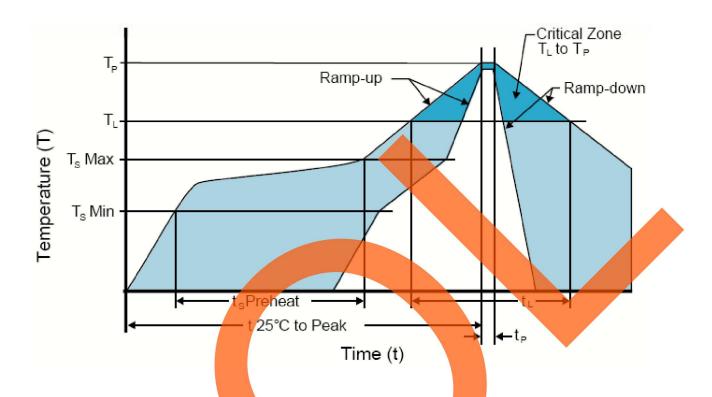
Quantity per Reel: 1,000 Units

All Dimensions in Millimeters
Compliant to EIA-481





RECOMMENDED SOLDER REFLOW METHOD



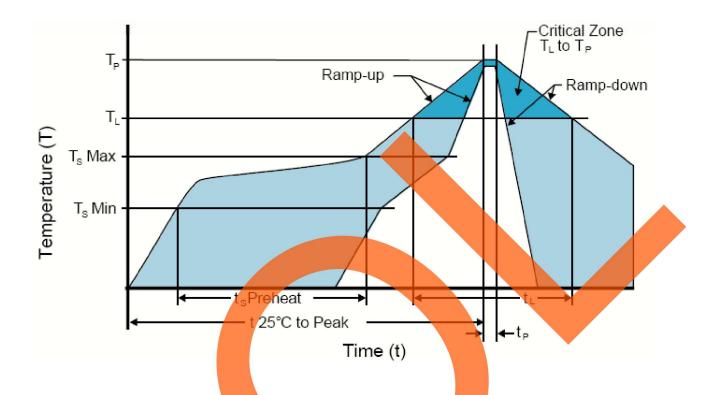
HIGH TEMPERATURE INFRARED/CONVECTION		
T _s MAX to T _L (Ramp-up Rate)	3°C/Second Maximum	
Preheat		
- Temperature Minimum (T _s MIN)	150°C	
- Temperature Typical (T _S TYP)	175°C	
- Temperature Maximum(T _s MAX)	200°C	
- Time (t _s)	60 - 180 Seconds	
Ramp-up Rate (T _L to T _P)	3°C/Second Maximum	
Time Maintained Above:		
- Temperature (T _L)	217°C	
- Time (t _L)	60 - 150 Seconds	
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum	
Target Peak Temperature(Tp Target)	250°C +0 <mark>/-5°C</mark>	
Time within 5°C of actual peak (tp)	20 - 40 Seconds	
Ramp-down Rate	6°C/Second Maximum	
Time 25°C to Peak Temperature (t)	8 Minutes Maximum	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)



RECOMMENDED SOLDER REFLOW METHOD



LOW TEMPERATURE INFRARED/CONVECTION		
T _s MAX to T _L (Ramp-up Rate)	5°C/Second Maximum	
Preheat		
- Temperature Minimum (T _s MIN)	N/A	
- Temperature Typical (Ts TYP)	150°C	
- Temperature Maximum(T _s MAX)	N/A	
- Time (t _s)	60 - 120 Seconds	
Ramp-up Rate (T _L to T _P)	5°C/Second Maximum	
Time Maintained Above:	<u> </u>	
- Temperature (T₋)	150°C	
- Time (t _L)	200 Seconds Maximum	
Peak Temperature (T _P)	240°C Maximum	
Target Peak Temperature(Tp Target)	240°C Maximum 2 Times/230°C Maximum 1Time	
Time within 5°C of actual peak (tp)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time	
Ramp-down Rate	5°C/Second Maximum	
Time 25°C to Peak Temperature (t)	N/A	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)